

Reg. No.:						:	
_		l	 		177.5	11 1	

Question Paper Code: 50453

B.E./B.Tech./B.Arch. DEGREE EXAMINATION, NOVEMBER/DECEMBER 2017 Seventh Semester

Electronics and Communication Engineering EC 6701 – RF AND MICROWAVE ENGINEERING (Regulations 2013)

Time: Three Hours

Maximum: 100 Marks

Answer ALL questions

PART - A

 $(10\times2=20 \text{ Marks})$

- 1. What are the limitations in measuring Z, Y and ABCD parameters at microwave frequencies.
- 2. Write down the merits and demerits of microwave frequency over lower frequencies.
- 3. Define unconditional stability with regard to microwave transistor amplifier.
- 4. Draw any two matching networks used in microwave frequencies.
- 5. Which has lesser coupling in the following?
 - i) 3 dB coupler
 - ii) 6 dB coupler
 - iii) 10 dB coupler.
- 6. What are ferrites and write its properties. Give some examples of ferrite devices.
- 7. What is the purpose of slow wave structures used in TWT amplifiers?
- 8. What do you mean by O type tube? Name some O type tubes.
- 9. Define return loss and insertion loss in RF networks.
- 10. What are the uses of network analyzer? What are the types of network analysers?

	PART - B	(5×16=80 Marks)
11. a) The S-parameters of a t $S_{12} = 0.5 \lfloor 90^{\circ}, S_{21} = 0.5 \rfloor$	two-port network are given by 510°.	$S_{11} = 0.2 \lfloor 90^{\circ}, S_{22} = 0.2 \lfloor 90^{\circ} \rfloor$
	er the network is lossy or not.	
b) is the network sym	imetrical and reciprocal	
c) ring the insertion	loss of network	•
d) Find the return los	ss at Port 1 when Port 2 is sho	out airrority I
(OR	?)	rt circuited.
	•	
S matrix.	x of multiport network and ex	xplain the properties of
ii) Write the property	of S-matrix	(12)
12. a) An RF amplifier has the	following Comments	(4)
impedance $ m Zs = 40\Omega$. 'amplifier of $ m Z_L = 73\Omega$ measured with referen	Solution of the second states	Vs = $5V \angle 0^{\circ}$ and source an antenna which has an atters of the amplifier are
(OR)	,	(16)
b) Discuss the following:	, , , , , , , , , , , , , , , , , , ,	•
i) Single stub in		
i) Single stub impedar	ace matching.	(8)
ii) Double stub impeda	nce matching.	(8)
13. a) Discuss the following:	_	(8+8)
i) Quarter wave transf	former ii) Gunn diode osc	illator.
(OR)		
b) Derive the S-matrix of h	ybrid Tee and discuss the prop	perties and applications (10)
14 a) Evaloin the	0	perties and applications. (16)
14. a) Explain the operation of performance characteris	freflex klystron oscillator with stics and applications of the re	n neat diagram. Write the eflex klystron.
(OR)	•	
b) Write a detailed notes or	n the following :	•
1) Travelling wave tube	e amplifier	(0)
ii) Cylindrical magnetro	on.	(8)
		(8)
, x	e of operation of VSWR meter	(8)
ii) Discuss the measure	ment of power at microwave f	requency in detail. (8)
(OR)	·	
b) i) Discuss the slotted lin	ne method of impedance meas	Illromant
ii) Explain how low VSV	VR can be measured using a r	\-\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
	and appropried astua a	nicrowave bench. (8)